CNB2001

Reflective Photosensor

For contactless SW and object detection

Overview

CNB2001 is a small, thin SMD-compatible reflective photosensor consisting of a high efficiency GaAs infrared light emitting diode which is integrated with a high sensitivity darlington phototransistor in a single resin package.

■ Features

- Reflow-compatible reflective photosensor
- Ultraminiature, thin type: 2.7 mm × 3.4 mm (height: 1.5 mm)
- Visible light cutoff resin is used
- High current transfer ratio

■ Absolute Maximum Ratings $T_a = 25$ °C

F	Symbol Rating		Unit	
Input (Light emitting diode)	Power dissipation *1	P_{D}	75	mW
	Forward current	I_{F}	50	mA
	Reverse voltage	V_R	6	V
Output (Photo transistor)	Collector-emitter voltage (Base open)	V _{CEO} 35		V
	Emitter-collector voltage (Base open)	V _{ECO}	6	V
	Collector current	I_{C}	30	mA
	Collector power dissipation *2	$P_{\rm C}$	75	mW
Operating ambient temp	T _{opr}	-25 to +85	°C	
Storage temperature	T _{stg}	-40 to +100	°C	

Note) *1: Input power derating ratio is 1.0 mW/°C at $T_a \geq 25 ^{\circ} C$

^{*2:} Output power derating ratio is 1.0 mW/°C at $T_a \ge 25$ °C

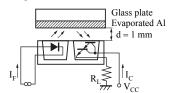
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■ Electrical-Optical Characteristics $T_a = 25$ °C±3°C

	Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input characteristics	Reverse current	I_R	$V_R = 3 V$			10	μΑ
	Forward voltage	V _F	$I_F = 20 \text{ mA}$		1.2	1.4	V
Output characteristics	Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 10 \text{ V}$			1.0	μΑ
Transfer characteristics	Collector current *1, *2	I_{C}	$V_{CC} = 2 \text{ V}, I_F = 4 \text{ mA},$ $R_L = 100 \Omega, d = 1 \text{ mm}$	0.52		15.00	mA
	Drain current	I_D	$V_{CC} = 2 \text{ V, } I_F = 4 \text{ mA,}$ $R_L = 100 \Omega$			5.0	μΑ
	Collector-emitter saturation voltage	V _{CE(sat)}	$I_F = 4 \text{ mA}, I_C = 0.5 \text{ mA}$			1.2	V
	Rise time *3	t _r	$V_{CC} = 2 \text{ V}, I_C = 10 \text{ mA},$		120		μs
	Fall time *3	t_{f}	$R_L = 100 \Omega$		115		μs

Note) 1. Input and output are practiced by electricity.

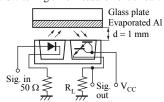
- 2. This device is designed by disregarding radiation.
- 3. *1: Output current measurement circuit

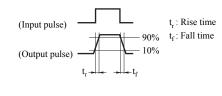


*2: Rank classification

Rank	Q	R	S
I _C (mA)	0.52 to 1.94	1.45 to 5.40	4.00 to 15.00
Color	Orange	White	Light blue

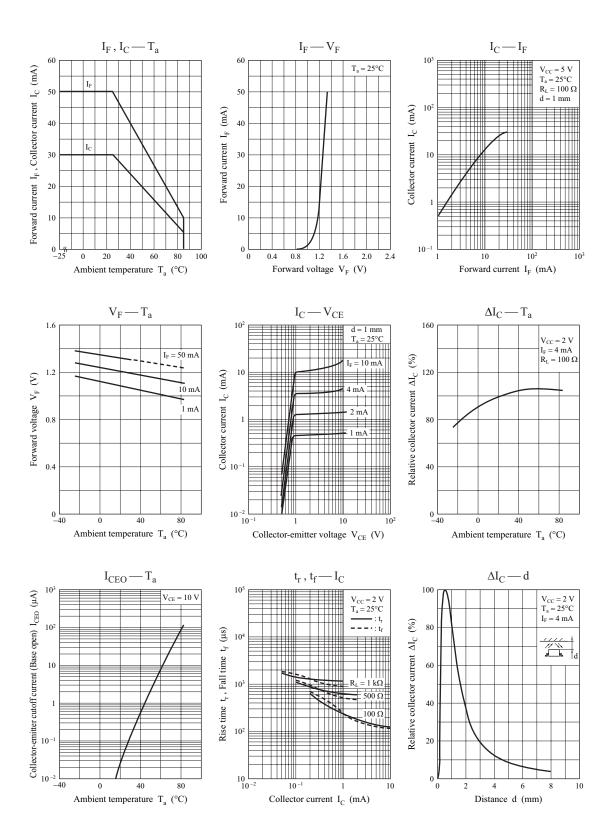
*3: Switching time measurement circuit





- t_{r} : Time required for the collector current to increase from 10% to 90% of its final value
- $t_{\rm f}$: Time required for the collector current to decrease from 90% to 10% of its initial value

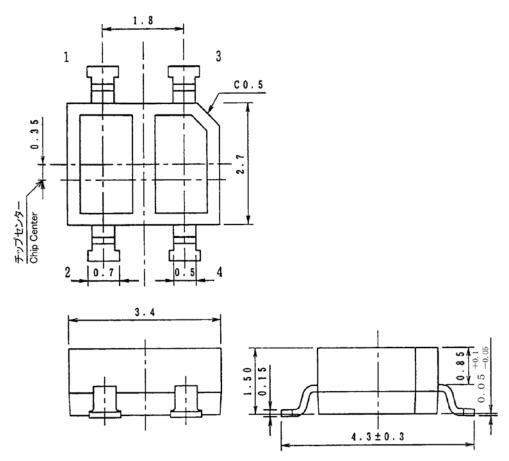
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■ Package (Unit: mm)

LSMFRN4G0001



(注1) 指示無き寸法公差は±0.2/

(Note1)Not appointment tolerance : ± 0.2 .

(注 2) マークは、目視又は顕微鏡に於いて解読できる事。

(Note2)What a date code sees an attention and can decode in a microscope.

- Pin name
 - 1: Anode
 - 2: Cathode
 - 3: Emitter
 - 4: Collector

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